



# PBSS4021SPN

20 V NPN/PNP low  $V_{CEsat}$  (BISS) transistor

Rev. 2 — 13 October 2010

Product data sheet

## 1. Product profile

### 1.1 General description

NPN/PNP low  $V_{CEsat}$  Breakthrough In Small Signal (BISS) transistor in a SOT96-1 (SO8) medium power Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package		NPN/PNP complement	PNP/PNP complement
	Nexperia	Name		
PBSS4021SPN	SOT96-1	SO8	PBSS4021SN	PBSS4021SP

### 1.2 Features and benefits

- Very low collector-emitter saturation voltage  $V_{CEsat}$
- High collector current capability  $I_C$  and  $I_{CM}$
- High collector current gain ( $h_{FE}$ ) at high  $I_C$
- High efficiency due to less heat generation
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors

### 1.3 Applications

- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>TR1; NPN low <math>V_{CEsat}</math> transistor</b>						
$V_{CEO}$	collector-emitter voltage	open base	-	-	20	V
$I_C$	collector current		-	-	7.5	A
$I_{CM}$	peak collector current	single pulse; $t_p \leq 1$ ms	-	-	15	A
$R_{CEsat}$	collector-emitter saturation resistance	$I_C = 5$ A; $I_B = 0.5$ A	[1] -	25	35	m $\Omega$

nexperia

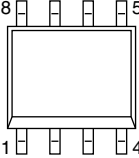
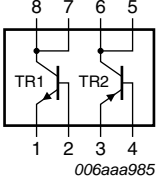
Table 2. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>TR2; PNP low <math>V_{CEsat}</math> transistor</b>						
$V_{CEO}$	collector-emitter voltage	open base	-	-	-20	V
$I_C$	collector current		-	-	-6.3	A
$I_{CM}$	peak collector current	single pulse; $t_p \leq 1$ ms	-	-	-15	A
$R_{CEsat}$	collector-emitter saturation resistance	$I_C = -5$ A; $I_B = -0.5$ A [1]	-	36	54	m $\Omega$

[1] Pulse test:  $t_p \leq 300$   $\mu$ s;  $\delta \leq 0.02$ .

## 2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	emitter TR1		
2	base TR1		
3	emitter TR2		
4	base TR2		
5	collector TR2		
6	collector TR2		
7	collector TR1		
8	collector TR1		

## 3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PBSS4021SPN	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

## 4. Marking

Table 5. Marking codes

Type number	Marking code
PBSS4021SPN	4021SPN

## 5. Limiting values

**Table 6. Limiting values**

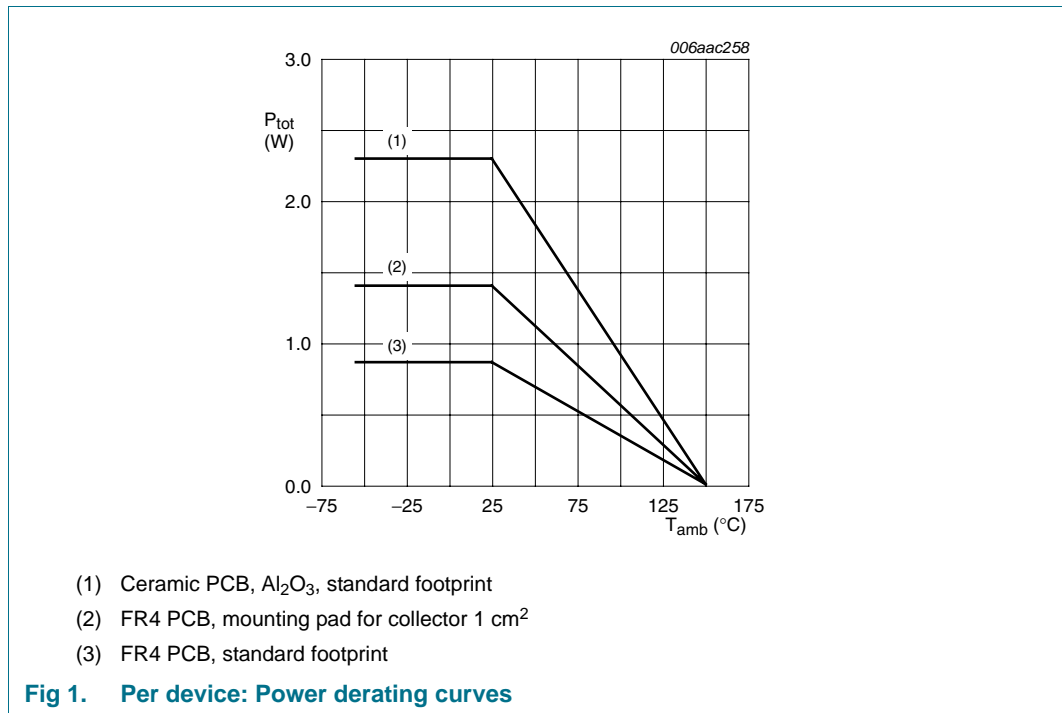
*In accordance with the Absolute Maximum Rating System (IEC 60134).*

Symbol	Parameter	Conditions	Min	Max	Unit	
<b>TR1 (NPN)</b>						
$I_C$	collector current		-	7.5	A	
<b>TR2 (PNP)</b>						
$I_C$	collector current		-	-6.3	A	
<b>Per transistor; for the PNP transistor with negative polarity</b>						
$V_{CBO}$	collector-base voltage	open emitter	-	20	V	
$V_{CEO}$	collector-emitter voltage	open base	-	20	V	
$V_{EBO}$	emitter-base voltage	open collector	-	5	V	
$I_{CM}$	peak collector current	single pulse; $t_p \leq 1$ ms	-	15	A	
$I_B$	base current		-	1	A	
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	-	0.73	W
			[2]	-	1	W
			[3]	-	1.7	W
<b>Per device</b>						
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	-	0.86	W
			[2]	-	1.4	W
			[3]	-	2.3	W
$T_j$	junction temperature		-	150	°C	
$T_{amb}$	ambient temperature		-55	+150	°C	
$T_{stg}$	storage temperature		-65	+150	°C	

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.



## 6. Thermal characteristics

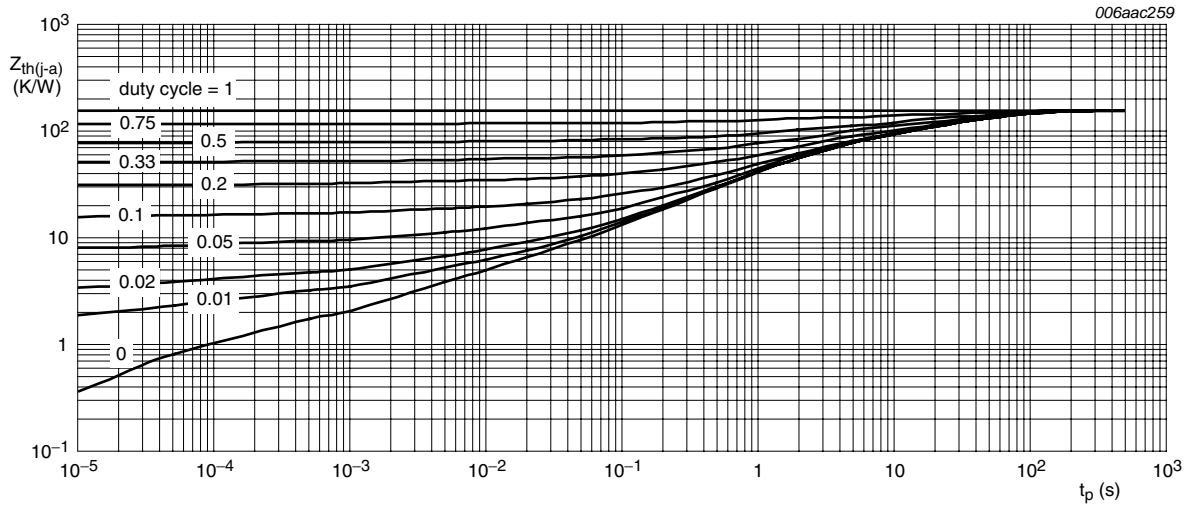
**Table 7. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>Per transistor</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	170	K/W
			[2]	-	-	125	K/W
			[3]	-	-	75	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	40	K/W	
<b>Per device</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	145	K/W
			[2]	-	-	90	K/W
			[3]	-	-	55	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

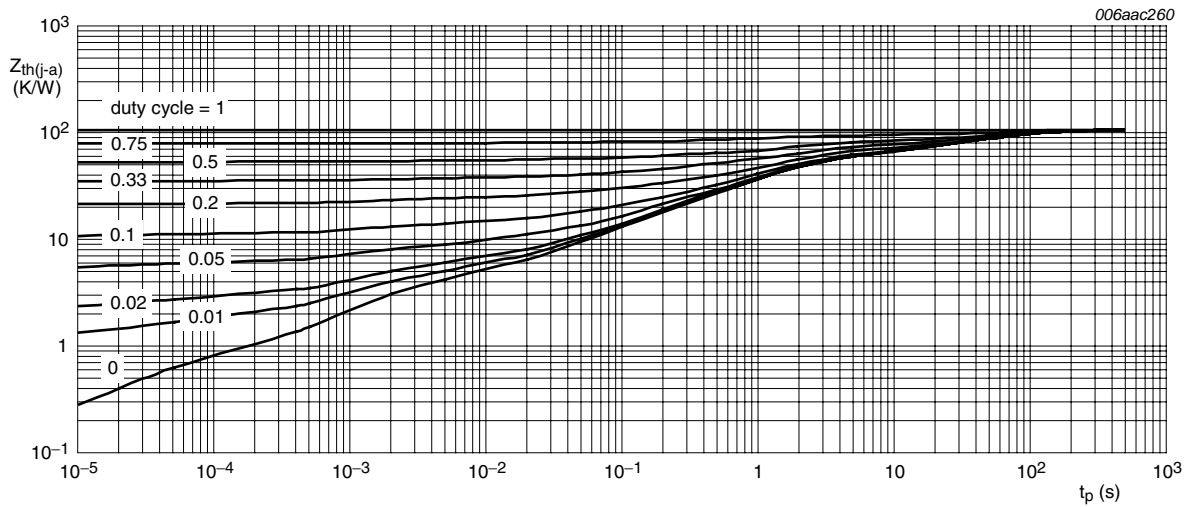
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.



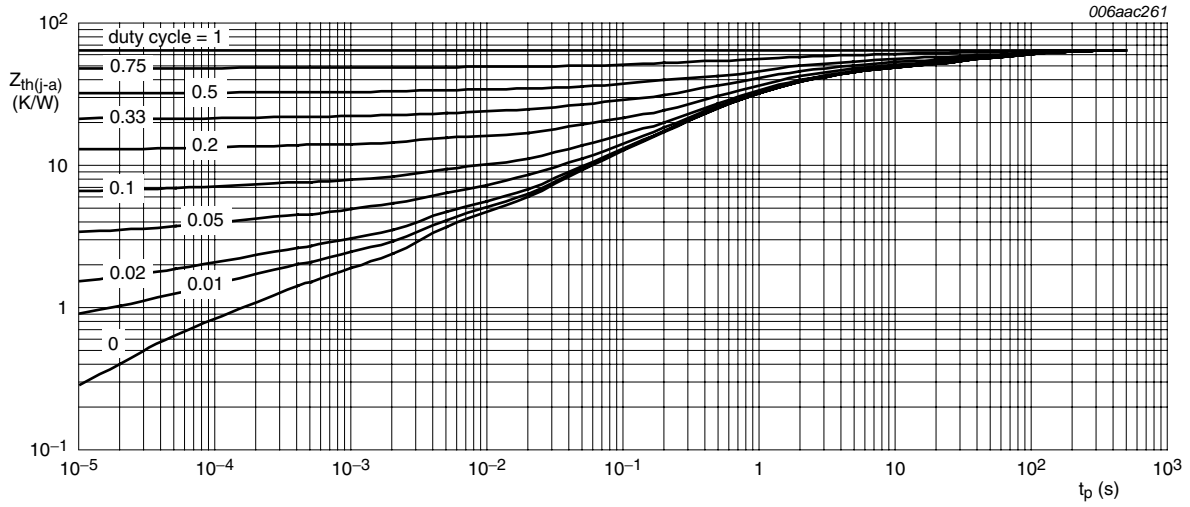
FR4 PCB, standard footprint

**Fig 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values**



FR4 PCB, mounting pad for collector 1 cm<sup>2</sup>

**Fig 3. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values**



Ceramic PCB,  $Al_2O_3$ , standard footprint

**Fig 4. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values**

## 7. Characteristics

**Table 8. Characteristics**
 $T_{amb} = 25\text{ °C}$  unless otherwise specified.

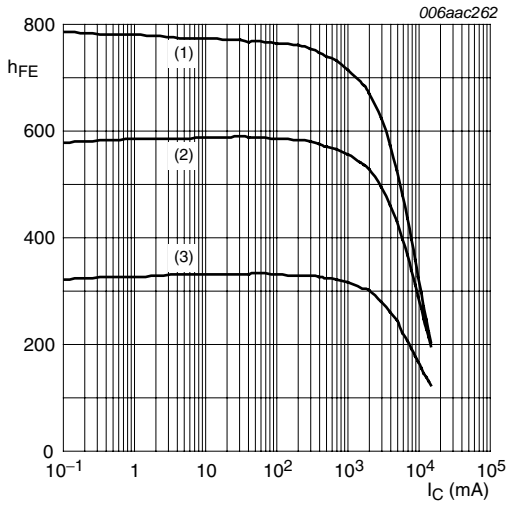
Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>TR1; NPN low <math>V_{CEsat}</math> transistor</b>							
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 20\text{ V}; I_E = 0\text{ A}$	-	-	100	nA	
		$V_{CB} = 20\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ °C}$	-	-	50	$\mu\text{A}$	
$I_{CES}$	collector-emitter cut-off current	$V_{CE} = 16\text{ V}; V_{BE} = 0\text{ V}$	-	-	100	nA	
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 5\text{ V}; I_C = 0\text{ A}$	-	-	100	nA	
$h_{FE}$	DC current gain	$V_{CE} = 2\text{ V}$	[1]				
		$I_C = 500\text{ mA}$	300	550	-		
		$I_C = 1\text{ A}$	300	550	-		
		$I_C = 2\text{ A}$	300	500	-		
		$I_C = 4\text{ A}$	250	450	-		
		$I_C = 8\text{ A}$	100	200	-		
$V_{CEsat}$	collector-emitter saturation voltage	[1]					
		$I_C = 1\text{ A}; I_B = 50\text{ mA}$	-	30	45	mV	
		$I_C = 1\text{ A}; I_B = 10\text{ mA}$	-	40	60	mV	
		$I_C = 2\text{ A}; I_B = 40\text{ mA}$	-	60	90	mV	
		$I_C = 4\text{ A}; I_B = 200\text{ mA}$	-	100	150	mV	
		$I_C = 4\text{ A}; I_B = 40\text{ mA}$	-	120	180	mV	
$R_{CEsat}$	collector-emitter saturation resistance	$I_C = 5\text{ A}; I_B = 500\text{ mA}$	[1]	-	25	35	$\text{m}\Omega$
$V_{BEsat}$	base-emitter saturation voltage	[1]					
		$I_C = 1\text{ A}; I_B = 100\text{ mA}$	-	0.87	1	V	
		$I_C = 4\text{ A}; I_B = 400\text{ mA}$	-	1.04	1.2	V	
$V_{BEon}$	base-emitter turn-on voltage	$V_{CE} = 2\text{ V}; I_C = 2\text{ A}$	[1]	-	0.76	0.85	V
$t_d$	delay time	$V_{CC} = 12.5\text{ V}; I_C = 1\text{ A}; I_{Bon} = 0.05\text{ A}; I_{Boff} = -0.05\text{ A}$	-	40	-	ns	
$t_r$	rise time		-	40	-	ns	
$t_{on}$	turn-on time		-	80	-	ns	
$t_s$	storage time		-	650	-	ns	
$t_f$	fall time		-	75	-	ns	
$t_{off}$	turn-off time		-	725	-	ns	
$f_T$	transition frequency	$V_{CE} = 10\text{ V}; I_C = 100\text{ mA}; f = 100\text{ MHz}$	-	115	-	MHz	
$C_C$	collector capacitance	$V_{CB} = 10\text{ V}; I_E = I_e = 0\text{ A}; f = 1\text{ MHz}$	-	85	-	pF	

**Table 8. Characteristics ...continued**  
 $T_{amb} = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>TR2; PNP low <math>V_{CEsat}</math> transistor</b>							
$I_{CBO}$	collector-base cut-off current	$V_{CB} = -20\text{ V}; I_E = 0\text{ A}$	-	-	-100	nA	
		$V_{CB} = -20\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ °C}$	-	-	-50	$\mu\text{A}$	
$I_{CES}$	collector-emitter cut-off current	$V_{CE} = -16\text{ V}; V_{BE} = 0\text{ V}$	-	-	-100	nA	
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = -5\text{ V}; I_C = 0\text{ A}$	-	-	-100	nA	
$h_{FE}$	DC current gain	$V_{CE} = -2\text{ V}$	[1]				
		$I_C = -500\text{ mA}$	250	400	-		
		$I_C = -1\text{ A}$	250	400	-		
		$I_C = -2\text{ A}$	200	350	-		
		$I_C = -4\text{ A}$	150	300	-		
$V_{CEsat}$	collector-emitter saturation voltage	$V_{CE} = -2\text{ V}$	[1]				
		$I_C = -1\text{ A}; I_B = -50\text{ mA}$	-	-45	-68	mV	
		$I_C = -1\text{ A}; I_B = -10\text{ mA}$	-	-70	-115	mV	
		$I_C = -2\text{ A}; I_B = -40\text{ mA}$	-	-100	-150	mV	
		$I_C = -4\text{ A}; I_B = -200\text{ mA}$	-	-150	-225	mV	
		$I_C = -4\text{ A}; I_B = -40\text{ mA}$	-	-250	-375	mV	
$R_{CEsat}$	collector-emitter saturation resistance	$I_C = -5\text{ A}; I_B = -500\text{ mA}$	[1]	-	36	54	$\text{m}\Omega$
$V_{BEsat}$	base-emitter saturation voltage	$V_{CE} = -2\text{ V}$	[1]				
		$I_C = -1\text{ A}; I_B = -100\text{ mA}$	-	-0.85	-1	V	
$V_{BEon}$	base-emitter turn-on voltage	$I_C = -4\text{ A}; I_B = -400\text{ mA}$	-	-1	-1.2	V	
		$V_{CE} = -2\text{ V}; I_C = -2\text{ A}$	[1]	-	-0.76	-0.85	V
$t_d$	delay time	$V_{CC} = -12.5\text{ V}; I_C = -1\text{ A}; I_{Bon} = -0.05\text{ A}; I_{Boff} = 0.05\text{ A}$	-	40	-	ns	
$t_r$	rise time		-	55	-	ns	
$t_{on}$	turn-on time		-	95	-	ns	
$t_s$	storage time		-	340	-	ns	
$t_f$	fall time		-	85	-	ns	
$t_{off}$	turn-off time		-	425	-	ns	
$f_T$	transition frequency	$V_{CE} = -10\text{ V}; I_C = -100\text{ mA}; f = 100\text{ MHz}$	-	105	-	MHz	
$C_c$	collector capacitance	$V_{CB} = -10\text{ V}; I_E = I_C = 0\text{ A}; f = 1\text{ MHz}$	-	95	-	pF	

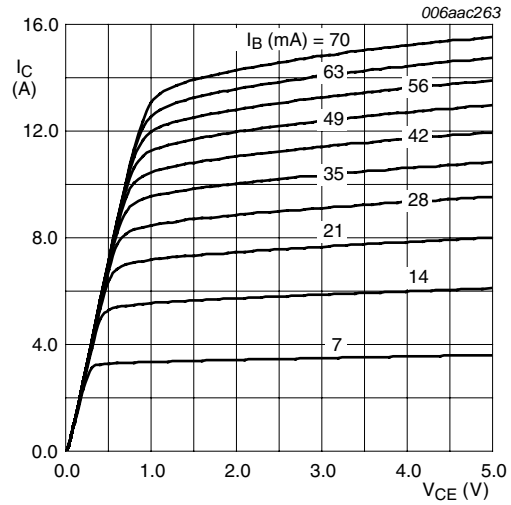
[1] Pulse test:  $t_p \leq 300\text{ }\mu\text{s}$ ;  $\delta \leq 0.02$ .





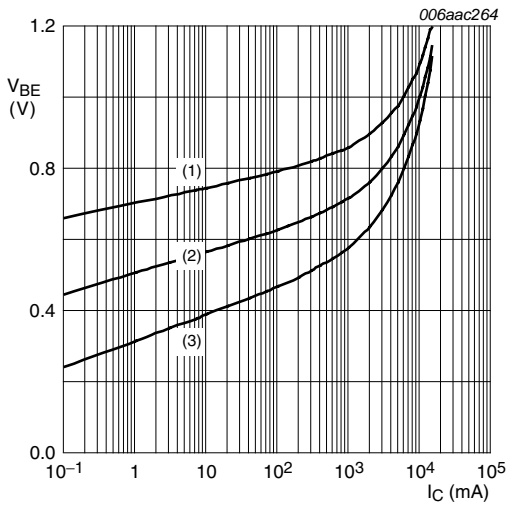
$V_{CE} = 2\text{ V}$   
 (1)  $T_{amb} = 100\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = -55\text{ }^{\circ}\text{C}$

**Fig 5. TR1 (NPN): DC current gain as a function of collector current; typical values**



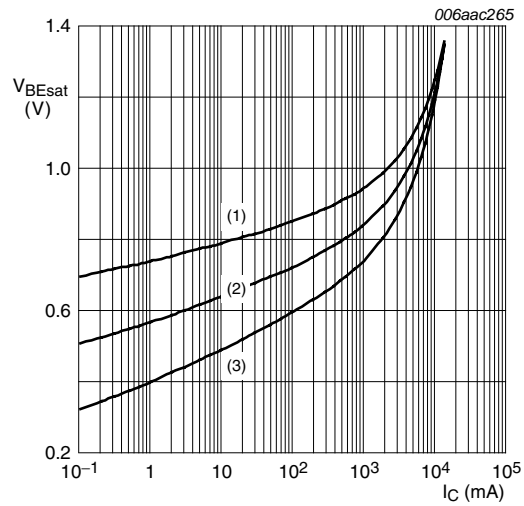
$T_{amb} = 25\text{ }^{\circ}\text{C}$

**Fig 6. TR1 (NPN): Collector current as a function of collector-emitter voltage; typical values**



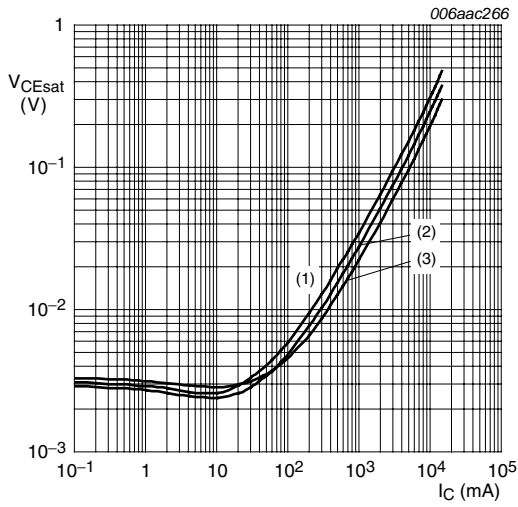
$V_{CE} = 2\text{ V}$   
 (1)  $T_{amb} = -55\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = 100\text{ }^{\circ}\text{C}$

**Fig 7. TR1 (NPN): Base-emitter voltage as a function of collector current; typical values**



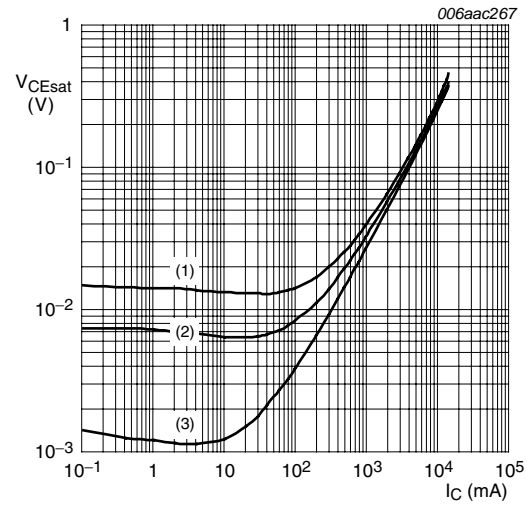
$I_C/I_B = 20$   
 (1)  $T_{amb} = -55\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = 100\text{ }^{\circ}\text{C}$

**Fig 8. TR1 (NPN): Base-emitter saturation voltage as a function of collector current; typical values**



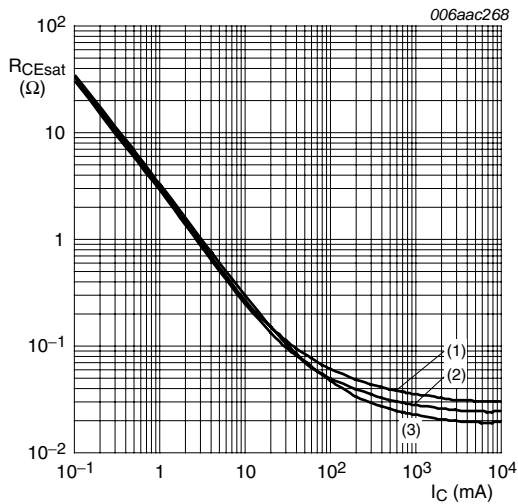
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -55\text{ °C}$

**Fig 9. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values**



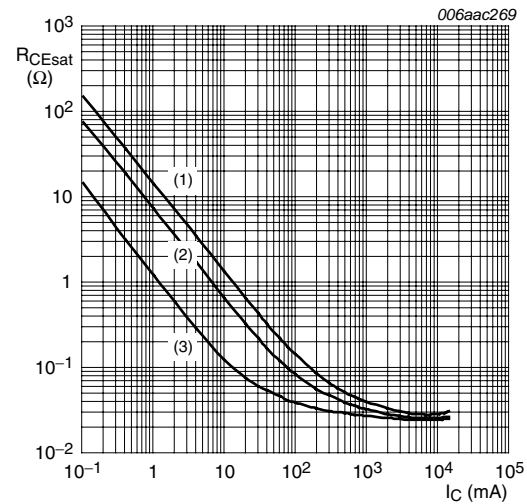
$T_{amb} = 25\text{ °C}$   
 (1)  $I_C/I_B = 100$   
 (2)  $I_C/I_B = 50$   
 (3)  $I_C/I_B = 10$

**Fig 10. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values**



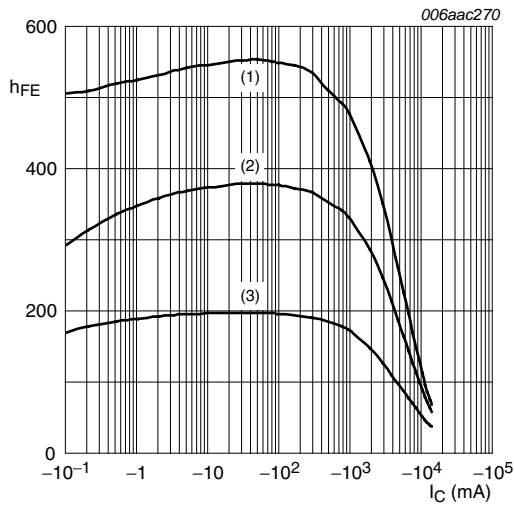
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -55\text{ °C}$

**Fig 11. TR1 (NPN): Collector-emitter saturation resistance as a function of collector current; typical values**



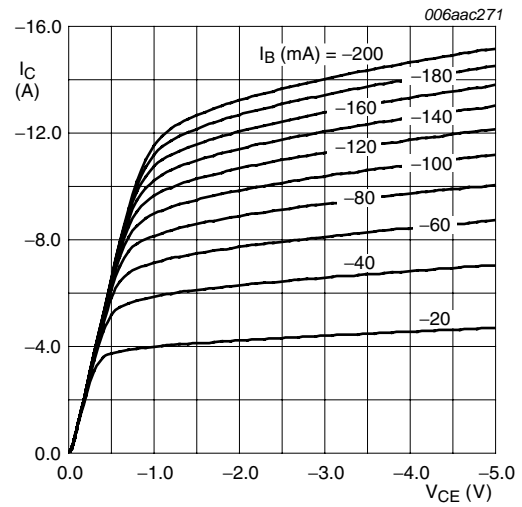
$T_{amb} = 25\text{ °C}$   
 (1)  $I_C/I_B = 100$   
 (2)  $I_C/I_B = 50$   
 (3)  $I_C/I_B = 10$

**Fig 12. TR1 (NPN): Collector-emitter saturation resistance as a function of collector current; typical values**



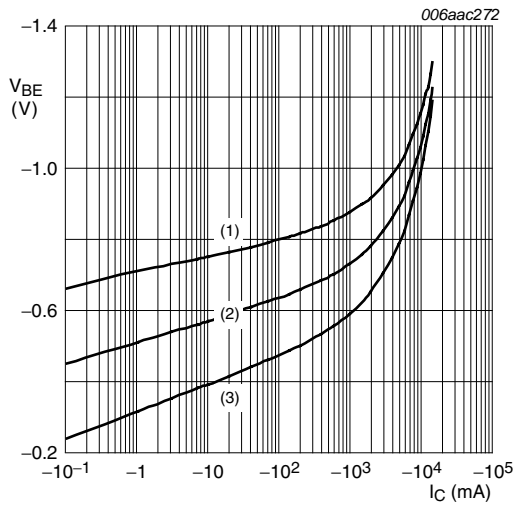
$V_{CE} = -2 \text{ V}$   
 (1)  $T_{amb} = 100 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -55 \text{ }^\circ\text{C}$

**Fig 13. TR2 (PNP): DC current gain as a function of collector current; typical values**



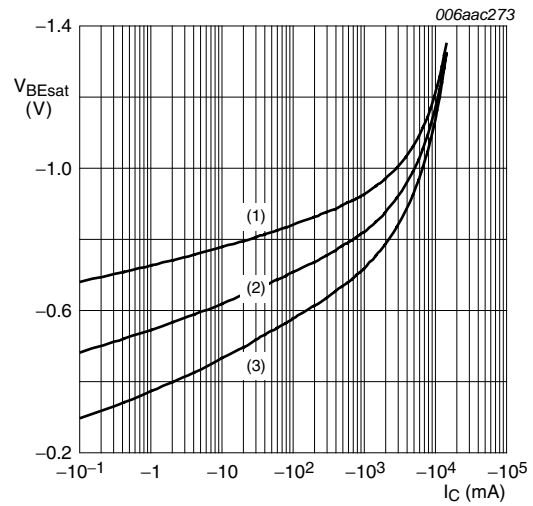
$T_{amb} = 25 \text{ }^\circ\text{C}$

**Fig 14. TR2 (PNP): Collector current as a function of collector-emitter voltage; typical values**



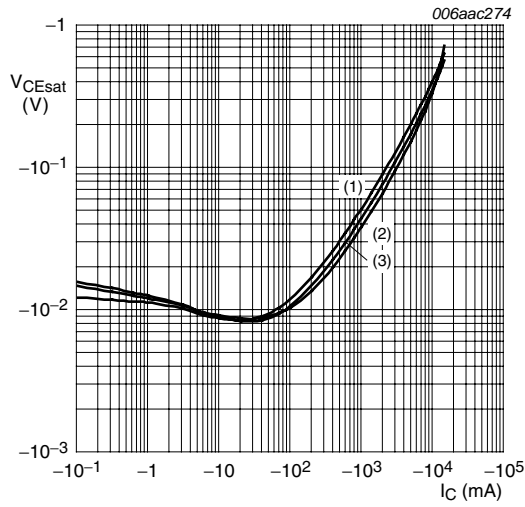
$V_{CE} = -2 \text{ V}$   
 (1)  $T_{amb} = -55 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100 \text{ }^\circ\text{C}$

**Fig 15. TR2 (PNP): Base-emitter voltage as a function of collector current; typical values**



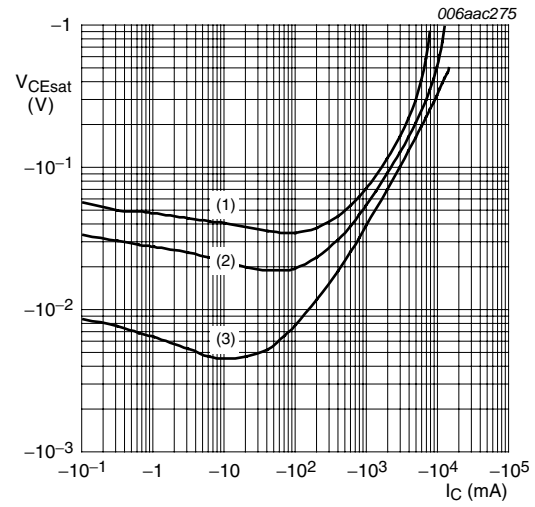
$I_C/I_B = 20$   
 (1)  $T_{amb} = -55 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100 \text{ }^\circ\text{C}$

**Fig 16. TR2 (PNP): Base-emitter saturation voltage as a function of collector current; typical values**



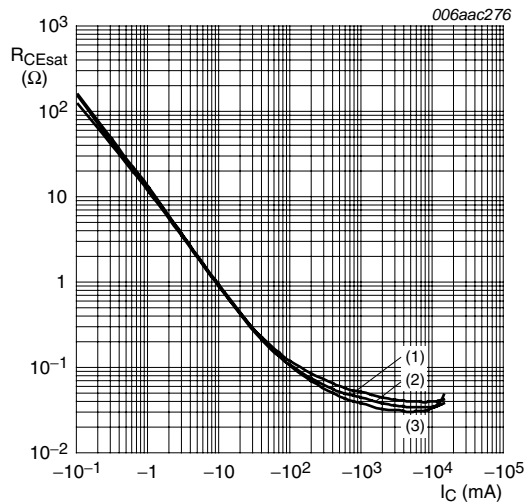
- $I_C/I_B = 20$
- (1)  $T_{amb} = 100\text{ °C}$
  - (2)  $T_{amb} = 25\text{ °C}$
  - (3)  $T_{amb} = -55\text{ °C}$

**Fig 17. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values**



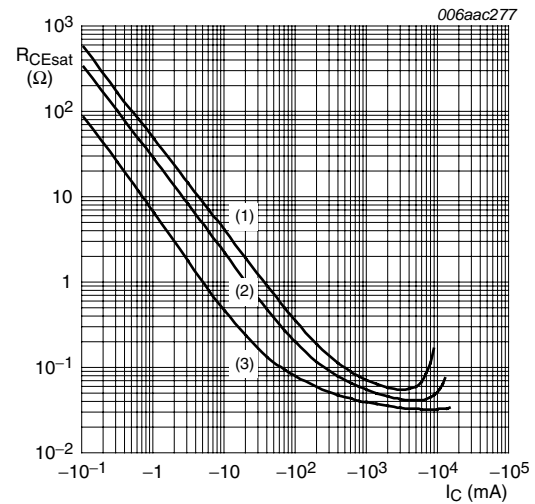
- $T_{amb} = 25\text{ °C}$
- (1)  $I_C/I_B = 100$
  - (2)  $I_C/I_B = 50$
  - (3)  $I_C/I_B = 10$

**Fig 18. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values**



- $I_C/I_B = 20$
- (1)  $T_{amb} = 100\text{ °C}$
  - (2)  $T_{amb} = 25\text{ °C}$
  - (3)  $T_{amb} = -55\text{ °C}$

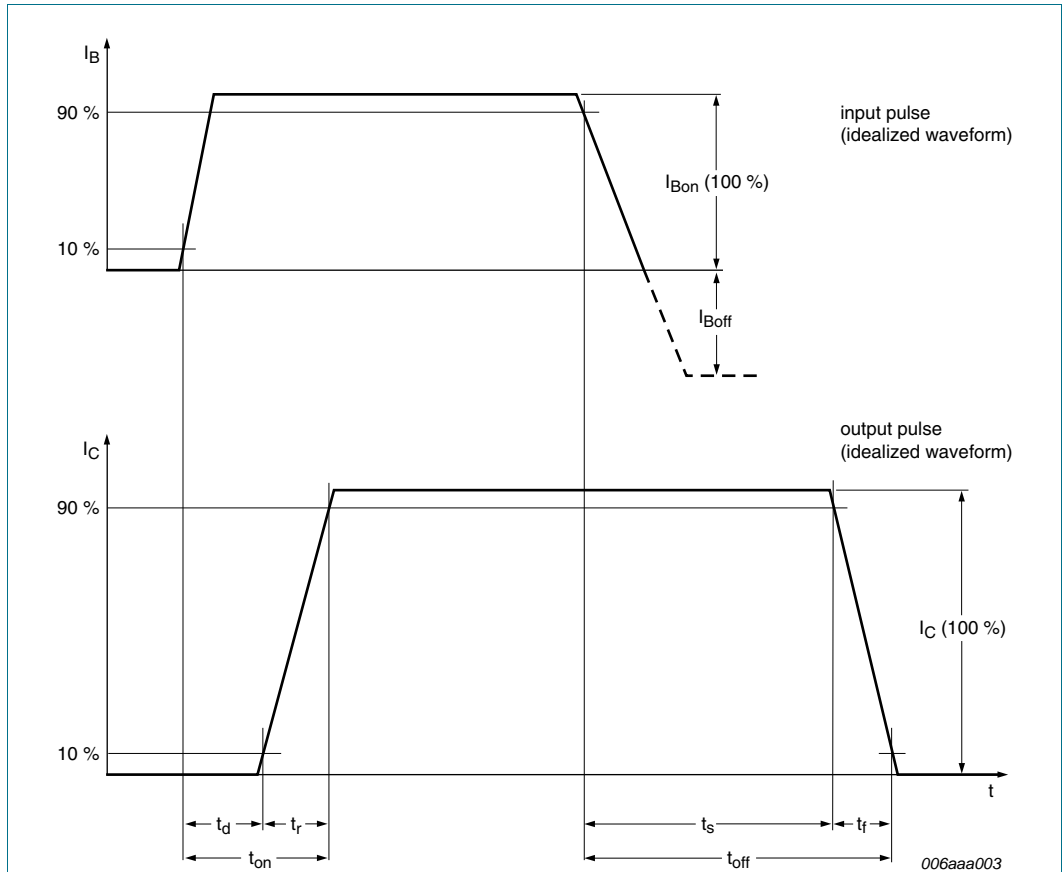
**Fig 19. TR2 (PNP): Collector-emitter saturation resistance as a function of collector current; typical values**



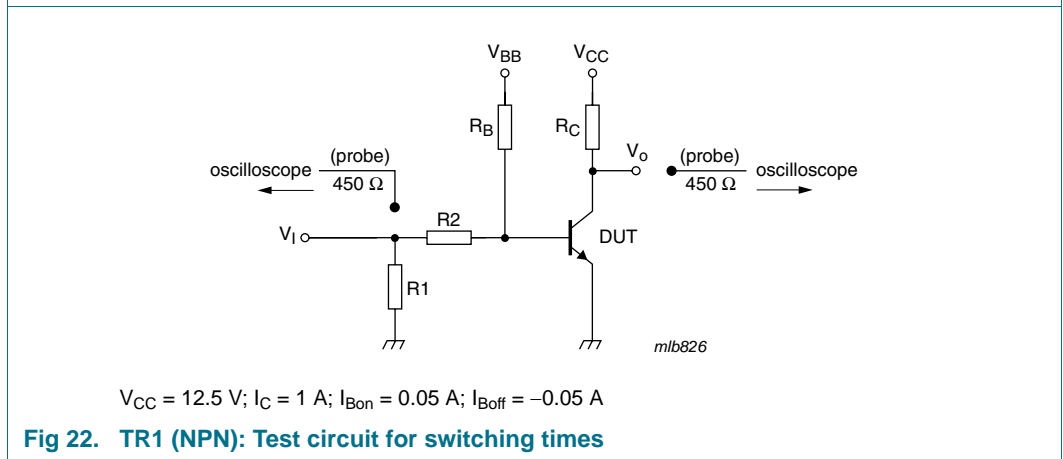
- $T_{amb} = 25\text{ °C}$
- (1)  $I_C/I_B = 100$
  - (2)  $I_C/I_B = 50$
  - (3)  $I_C/I_B = 10$

**Fig 20. TR2 (PNP): Collector-emitter saturation resistance as a function of collector current; typical values**

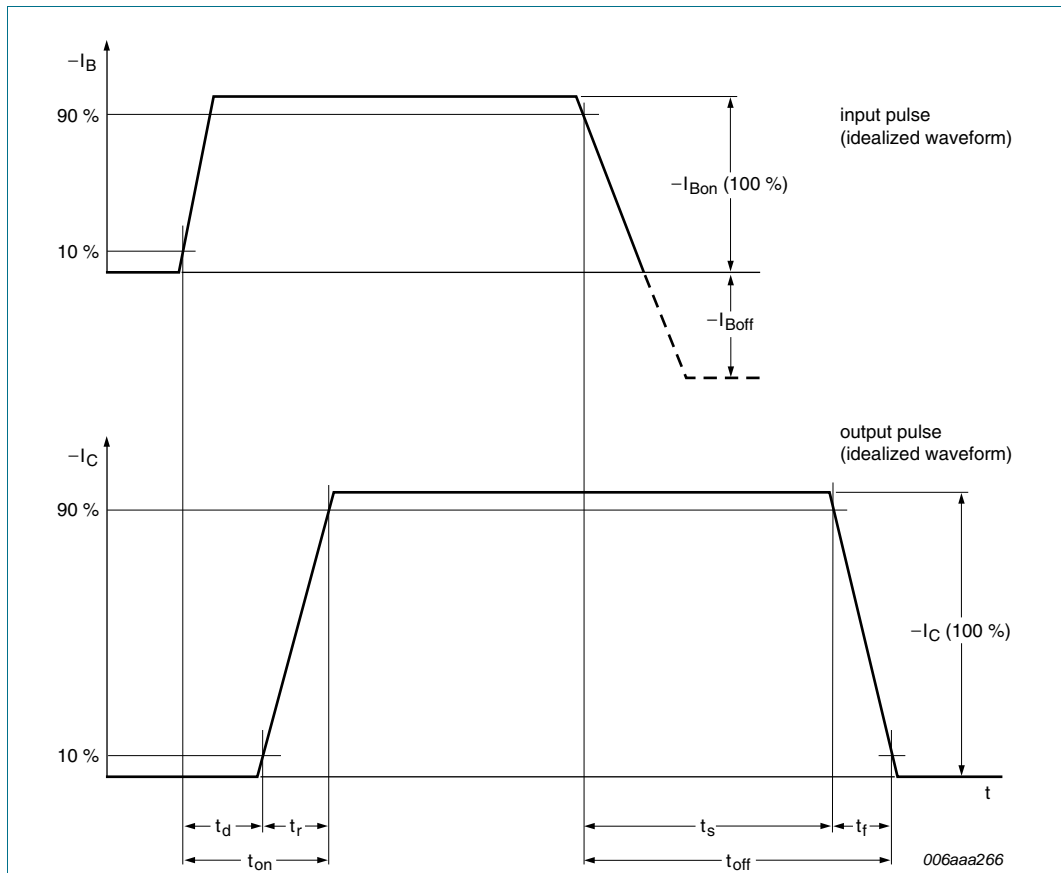
**8. Test information**



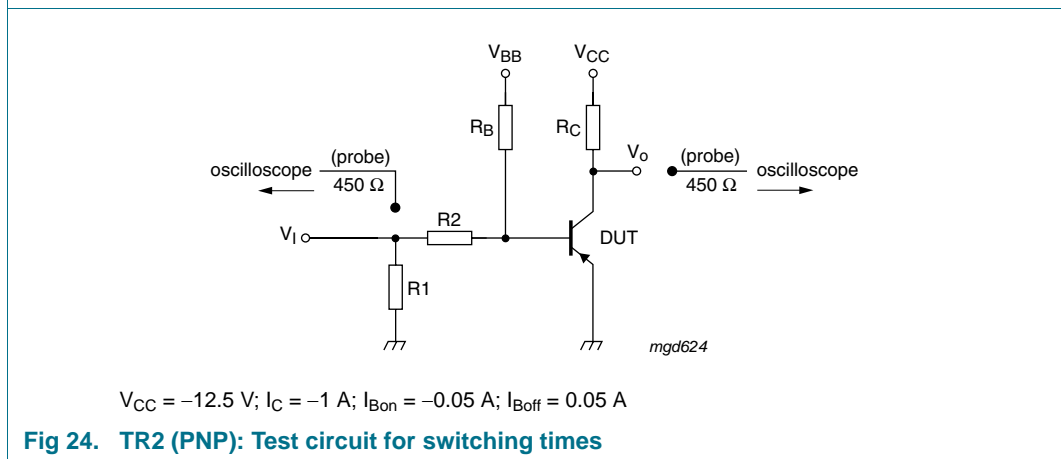
**Fig 21. TR1 (NPN): BISS transistor switching time definition**



**Fig 22. TR1 (NPN): Test circuit for switching times**

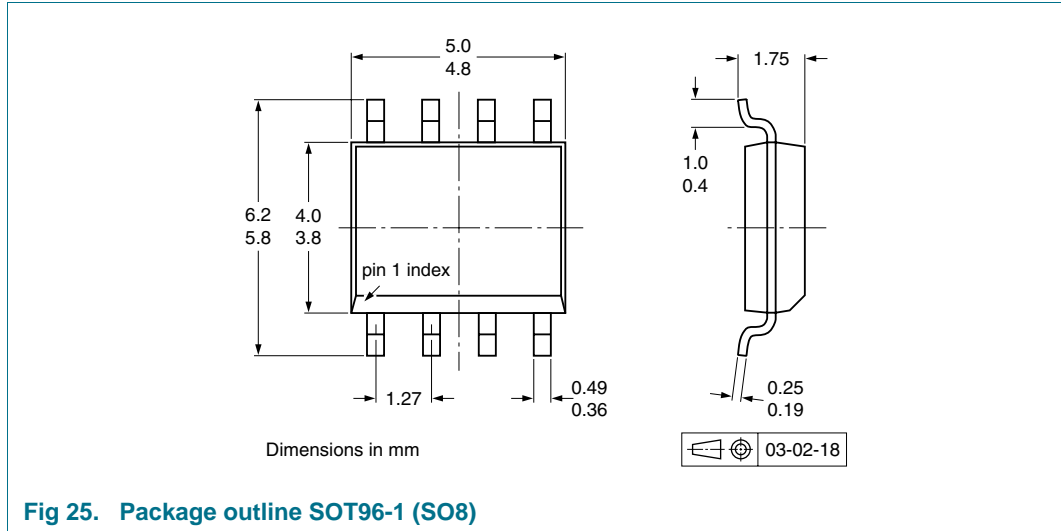


**Fig 23. TR2 (PNP): BISS transistor switching time definition**



**Fig 24. TR2 (PNP): Test circuit for switching times**

## 9. Package outline



## 10. Packing information

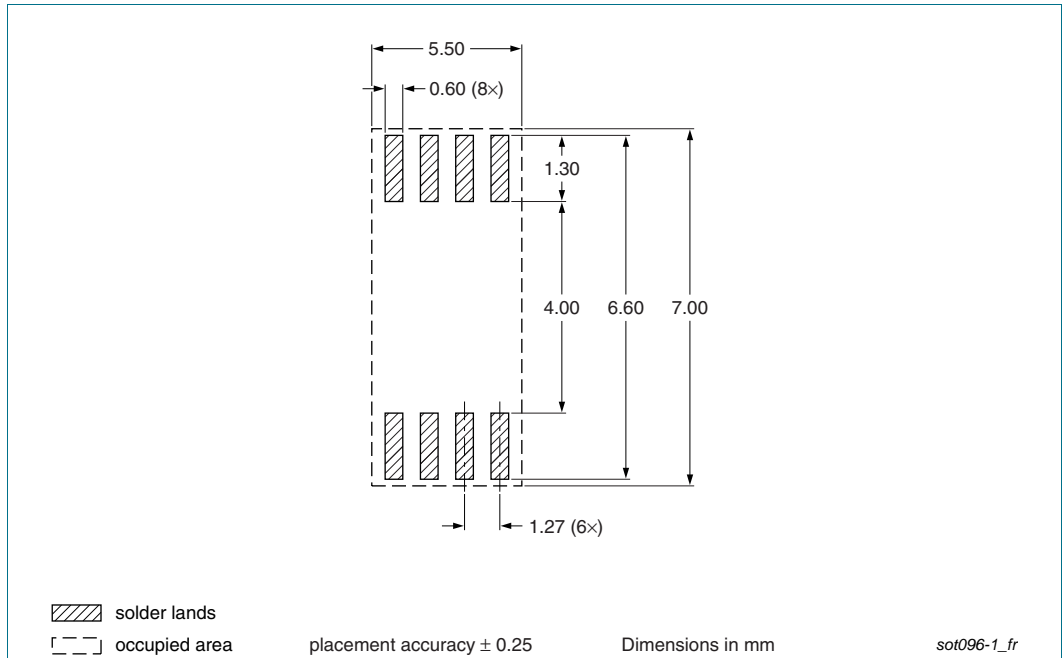
**Table 9. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

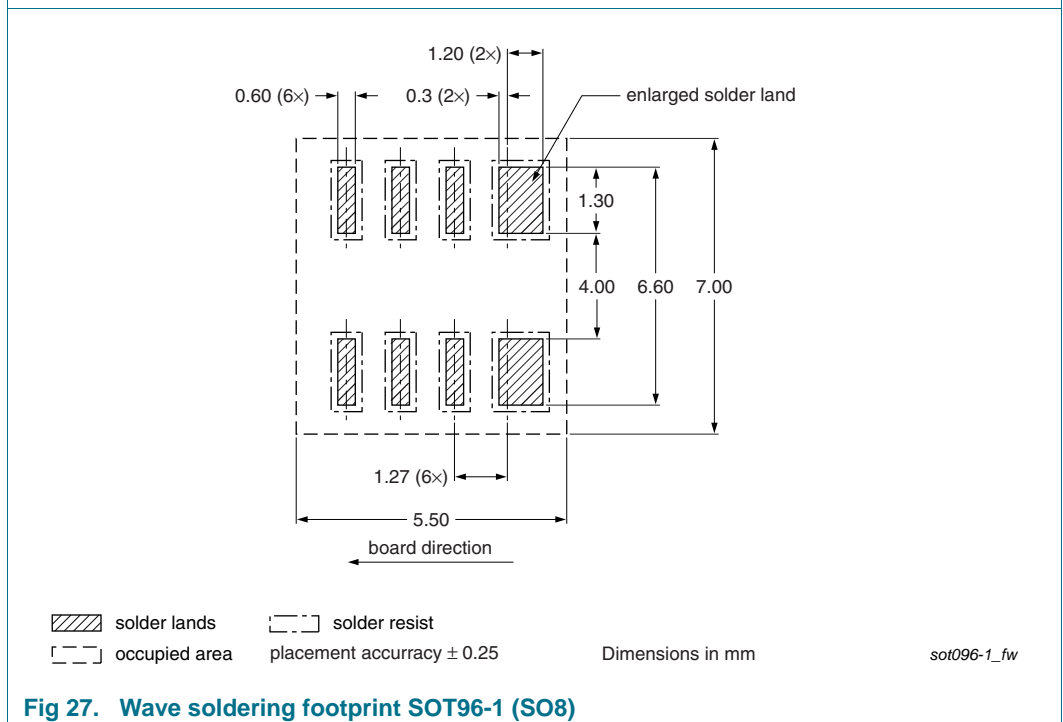
Type number	Package	Description	Packing quantity	
			1000	2500
PBSS4021SPN	SOT96-1	8 mm pitch, 12 mm tape and reel	-115	-118

[1] For further information and the availability of packing methods, see [Section 14](#).

## 11. Soldering



**Fig 26. Reflow soldering footprint SOT96-1 (SO8)**



**Fig 27. Wave soldering footprint SOT96-1 (SO8)**



## 12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4021SPN v.2	20101013	Product data sheet	-	PBSS4021SPN v.1
Modifications:	• <a href="#">Figure 1 "Per device: Power derating curves"</a> : updated.			
PBSS4021SPN v.1	20100714	Product data sheet	-	-

## 13. Legal information

### 13.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

### 13.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

**Short data sheet** — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

### 13.3 Disclaimers

**Limited warranty and liability** — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Nexperia.

**Right to make changes** — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or

malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia accepts no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

**Terms and conditions of commercial sale** — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nexperia.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

## 13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 14. Contact information

---

For more information, please visit: <http://www.nexperia.com>

For sales office addresses, please send an email to: [salesaddresses@nexperia.com](mailto:salesaddresses@nexperia.com)

## 15. Contents

<b>1</b>	<b>Product profile</b> . . . . .	<b>1</b>
1.1	General description . . . . .	1
1.2	Features and benefits . . . . .	1
1.3	Applications . . . . .	1
1.4	Quick reference data . . . . .	1
<b>2</b>	<b>Pinning information</b> . . . . .	<b>2</b>
<b>3</b>	<b>Ordering information</b> . . . . .	<b>2</b>
<b>4</b>	<b>Marking</b> . . . . .	<b>2</b>
<b>5</b>	<b>Limiting values</b> . . . . .	<b>3</b>
<b>6</b>	<b>Thermal characteristics</b> . . . . .	<b>4</b>
<b>7</b>	<b>Characteristics</b> . . . . .	<b>7</b>
<b>8</b>	<b>Test information</b> . . . . .	<b>13</b>
<b>9</b>	<b>Package outline</b> . . . . .	<b>15</b>
<b>10</b>	<b>Packing information</b> . . . . .	<b>15</b>
<b>11</b>	<b>Soldering</b> . . . . .	<b>16</b>
<b>12</b>	<b>Revision history</b> . . . . .	<b>17</b>
<b>13</b>	<b>Legal information</b> . . . . .	<b>18</b>
13.1	Data sheet status . . . . .	18
13.2	Definitions . . . . .	18
13.3	Disclaimers . . . . .	18
13.4	Trademarks . . . . .	19
<b>14</b>	<b>Contact information</b> . . . . .	<b>19</b>
<b>15</b>	<b>Contents</b> . . . . .	<b>20</b>